# NSN 5962-01-412-5563

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# Operating Tempurature Range:

-55.0/+125.0 degrees celsius

# Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

#### **Terminal Surface Treatment:**

Solder

#### **Product Name:**

Programmed cmos 65k x 8 uveprom

# Voltage Rating And Type Per Characteristic:

6.25 volts power source

#### Time Rating Per Chacteristic:

150.00 nanoseconds access

#### Memory Device Type:

Eprom

#### Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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